## MBRM120L

# **Surface Mount Schottky Power Rectifier**

## POWERMITE® Power Surface Mount Package

The Schottky Powermite<sup>®</sup> employs the Schottky Barrier principle with a barrier metal and epitaxial construction that produces optimal forward voltage drop–reverse current tradeoff. The advanced packaging techniques provide for a highly efficient micro miniature, space saving surface mount Rectifier. With its unique heatsink design, the Powermite<sup>®</sup> has the same thermal performance as the SMA while being 50% smaller in footprint area, and delivering one of the lowest height profiles, < 1.1 mm in the industry. Because of its small size, it is ideal for use in portable and battery powered products such as cellular and cordless phones, chargers, notebook computers, printers, PDAs and PCMCIA cards. Typical applications are AC–DC and DC–DC converters, reverse battery protection, and "ORing" of multiple supply voltages and any other application where performance and size are critical.

#### **Features**

- Low Profile Maximum Height of 1.1 mm
- Small Footprint Footprint Area of 8.45 mm<sup>2</sup>
- Low V<sub>F</sub> Provides Higher Efficiency and Extends Battery Life
- Supplied in 12 mm Tape and Reel
- Low Thermal Resistance with Direct Thermal Path of Die on Exposed Cathode Heat Sink
- ESD Ratings: Human Body Model, 3B > 16000 V Machine Model, C > 400 V
- Pb-Free Packages are Available

#### **Mechanical Characteristics:**

- Powermite<sup>®</sup> is JEDEC Registered as D0–216AA
- Case: Molded Epoxy
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 16.3 mg (Approximately)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Maximum for 10 Seconds



### ON Semiconductor®

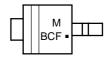
http://onsemi.com

## SCHOTTKY BARRIER RECTIFIER 1.0 AMPERES, 20 VOLTS



POWERMITE CASE 457 PLASTIC

#### **MARKING DIAGRAM**



M = Date CodeBCF = Device Code■ Pb-Free Package

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MBRM120LT1	POWERMITE	3000/Tape & Reel
MBRM120LT1G	POWERMITE (Pb-Free)	3000/Tape & Reel
MBRM120LT3	POWERMITE	12000/Tape & Reel
MBRM120LT3G	POWERMITE (Pb-Free)	12000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	20	V
Average Rectified Forward Current (At Rated V <sub>R</sub> , T <sub>C</sub> = 135°C)	Io	1.0	Α
Peak Repetitive Forward Current (At Rated V <sub>R</sub> , Square Wave, 100 kHz, T <sub>C</sub> = 135°C)	I <sub>FRM</sub>	2.0	А
Non-Repetitive Peak Surge Current (Non-Repetitive peak surge current, halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	50	А
Storage Temperature	T <sub>stg</sub>	-55 to 150	°C
Operating Junction Temperature	TJ	-55 to 125	°C
Voltage Rate of Change (Rated V <sub>R</sub> , T <sub>J</sub> = 25°C)	dv/dt	10,000	V/μs

#### THERMAL CHARACTERISTICS

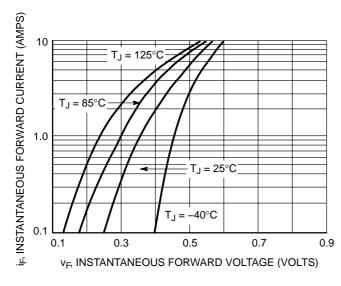
Thermal Resistance, Junction-to-Lead (Anode) (Note 1)	$R_{tjl}$	35	°C/W	ĺ
Thermal Resistance, Junction-to-Tab (Cathode) (Note 1)	R <sub>tjtab</sub>	23		ĺ
Thermal Resistance, Junction-to-Ambient (Note 1)	R <sub>tja</sub>	277		

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

Maximum Instantaneous Forward Voltage (Note 2), See Figure 2	V <sub>F</sub>	T <sub>J</sub> = 25°C	T <sub>J</sub> = 85°C	V
$(I_F = 0.1 \text{ A})$		0.34	0.26	
$(I_F = 1.0 \text{ A})$		0.45	0.415	
$(I_F = 3.0 \text{ A})$		0.65	0.67	
Maximum Instantaneous Reverse Current (Note 2), See Figure 4	I <sub>R</sub>	T <sub>J</sub> = 25°C	T <sub>J</sub> = 85°C	mA
(V <sub>R</sub> = 20 V)		0.40	25	
(V <sub>R</sub> = 10 V)		0.10	18	

<sup>2.</sup> Pulse Test: Pulse Width  $\leq$  250  $\mu$ s, Duty Cycle  $\leq$  2%.





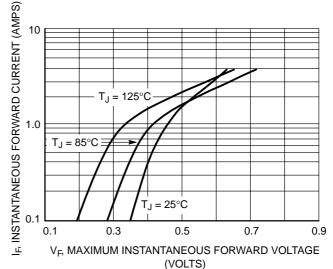


Figure 2. Maximum Forward Voltage

<sup>1.</sup> Mounted with minimum recommended pad size, PC Board FR4, See Figures 9 & 10.

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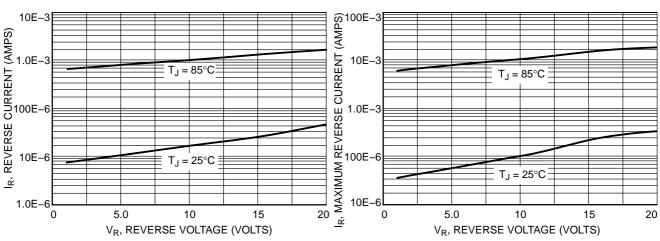


Figure 3. Typical Reverse Current

Figure 4. Maximum Reverse Current

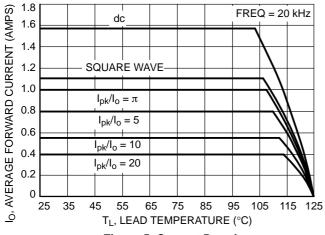


Figure 5. Current Derating

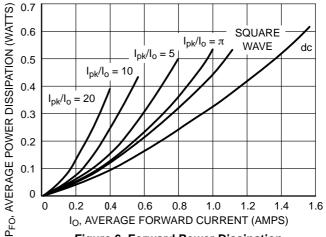
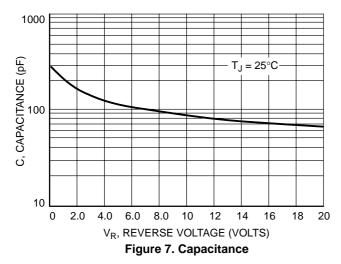


Figure 6. Forward Power Dissipation



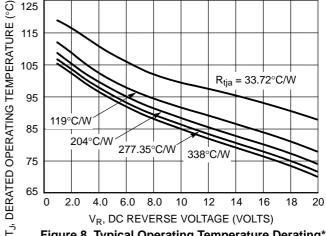


Figure 8. Typical Operating Temperature Derating\*

r(t) = thermal impedance under given conditions,

Pf = forward power dissipation, and

Pr = reverse power dissipation

This graph displays the derated allowable  $T_J$  due to reverse bias under DC conditions only and is calculated as  $T_J = T_{Jmax} - r(t)Pr$ , where r(t) = Rthja. For other power applications further calculations must be performed.

<sup>\*</sup> Reverse power dissipation and the possibility of thermal runaway must be considered when operating this device under any reverse voltage conditions. Calculations of T<sub>J</sub> therefore must include forward and reverse power effects. The allowable operating  $T_J = T_{Jmax} - r(t)(Pf + Pr)$  where T<sub>.I</sub> may be calculated from the equation:

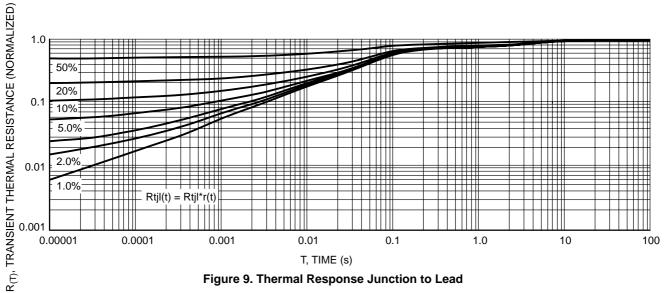


Figure 9. Thermal Response Junction to Lead

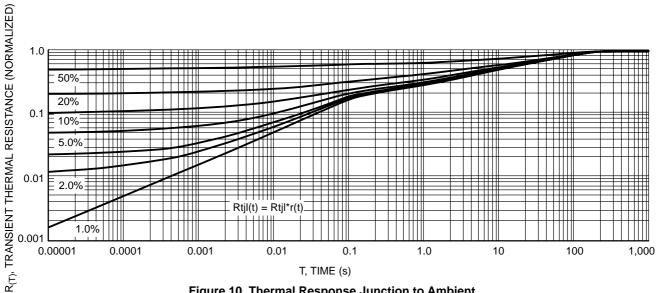


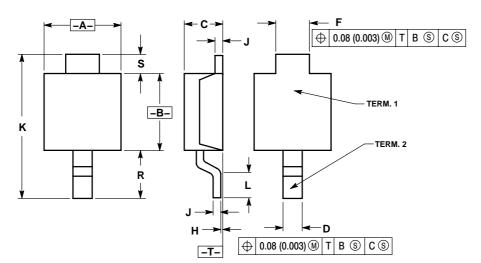
Figure 10. Thermal Response Junction to Ambient

#### MBRM120L

#### PACKAGE DIMENSIONS

#### **POWERMITE**

CASE 457-04 ISSUE D

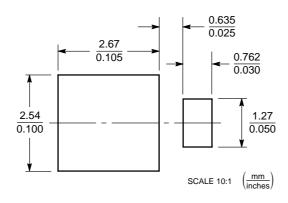


#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
  Y14.5M, 1982.
- . CONTROLLING DIMENSION: MILLIMETER
- DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	1.75	2.05	0.069	0.081
В	1.75	2.18	0.069	0.086
С	0.85	1.15	0.033	0.045
D	0.40	0.69	0.016	0.027
F	0.70	1.00	0.028	0.039
Н	-0.05	+0.10	-0.002	+0.004
7	0.10	0.25	0.004	0.010
K	3.60	3.90	0.142	0.154
L	0.50	0.80	0.020	0.031
R	1.20	1.50	0.047	0.059
9	0 50 DEE		0.010 RFF	

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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